



# BUK758R3-40E

N-channel TrenchMOS standard level FET

11 September 2012

Product data sheet

## 1. Product profile

### 1.1 General description

Standard level N-channel MOSFET in a SOT78 package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

### 1.2 Features and benefits

- AEC Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with VGS(th) rating of greater than 1V at 175 °C

### 1.3 Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

### 1.4 Quick reference data

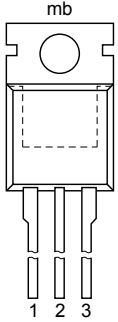
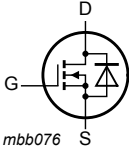
Table 1. Quick reference data

| Symbol                         | Parameter                        | Conditions   | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|--|-----|-----|-----|------|
| V <sub>DS</sub>                | drain-source voltage             | T <sub>j</sub> ≥ 25 °C; T <sub>j</sub> ≤ 175 °C  | -   | -   | 40  | V    |
| I <sub>D</sub>                 | drain current                    | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <a href="#">Fig. 1</a>  | [1] | -   | 75  | A    |
| P <sub>tot</sub>               | total power dissipation          | T <sub>mb</sub> = 25 °C; <a href="#">Fig. 2</a>  | -   | -   | 96  | W    |
| <b>Static characteristics</b>  |                                  |  |     |     |     |      |
| R <sub>DSon</sub>              | drain-source on-state resistance | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 20 A; T <sub>j</sub> = 25 °C; <a href="#">Fig. 11</a>                           | -   | 5.8 | 7.4 | mΩ   |
| <b>Dynamic characteristics</b> |                                  |  |     |     |     |      |
| Q <sub>GD</sub>                | gate-drain charge                | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 20 A; V <sub>DS</sub> = 32 V; <a href="#">Fig. 13</a> ; <a href="#">Fig. 14</a> | -   | 7.4 | -   | nC   |

[1] Continuous current is limited by package.

## 2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description                       | Simplified outline   | Graphic symbol  |
|-----|--------|-----------------------------------|--|---|
| 1   | G      | gate                              |  <p>TO-220AB (SOT78A)</p> |  <p>mbb076</p> |
| 2   | D      | drain                             |  |   |
| 3   | S      | source                            |  |   |
| mb  | D      | mounting base; connected to drain |  |   |

## 3. Ordering information

Table 3. Ordering information

| Type number  | Package  |  |         |
|--------------|----------|--|---------|
|              | Name     | Description  | Version |
| BUK758R3-40E | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78A  |

## 4. Marking

Table 4. Marking codes

| Type number  | Marking code |
|--------------|--------------|
| BUK758R3-40E | BUK758R3-40E |

## 5. Limiting values

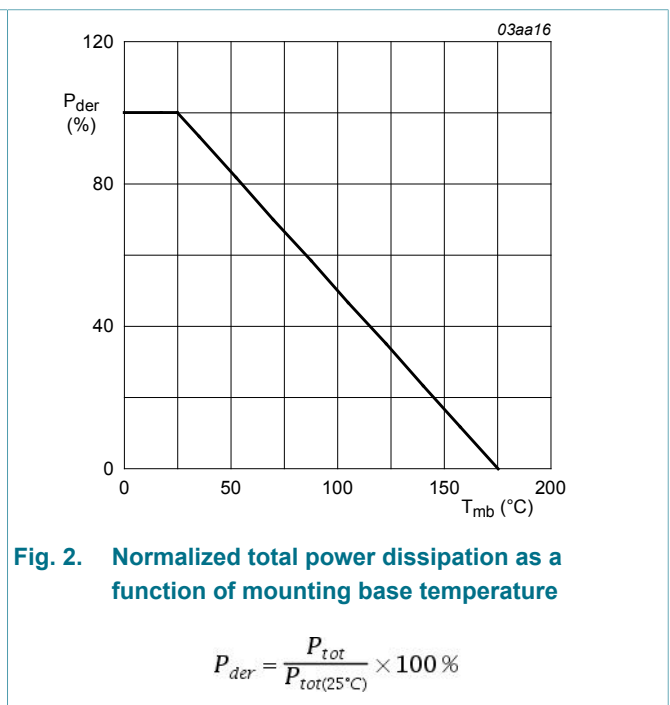
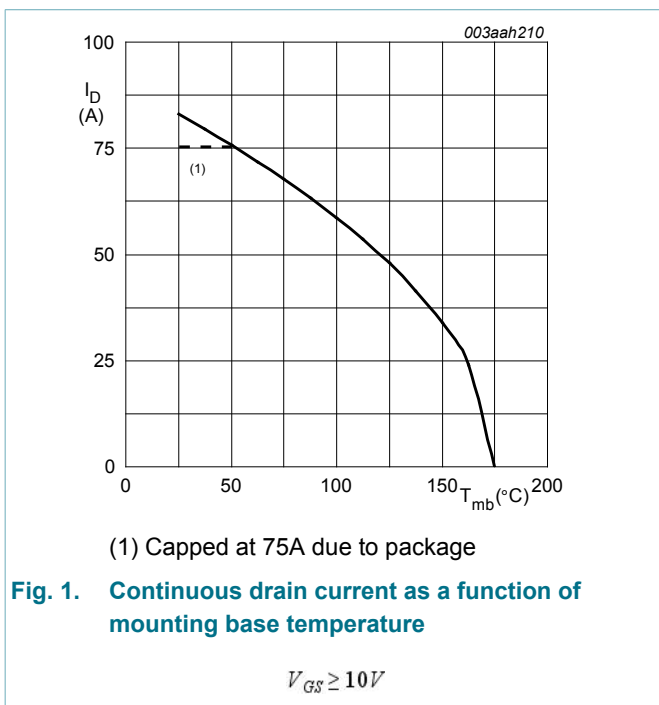
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter            | Conditions  |     | Min | Max | Unit |
|-----------|----------------------|---|-----|-----|-----|------|
| $V_{DS}$  | drain-source voltage | $T_j \geq 25\text{ °C}$ ; $T_j \leq 175\text{ °C}$                          |     | -   | 40  | V    |
| $V_{DGR}$ | drain-gate voltage   | $R_{GS} = 20\text{ k}\Omega$  |     | -   | 40  | V    |
| $V_{GS}$  | gate-source voltage  | $T_j \leq 175\text{ °C}$ ; DC   |     | -20 | 20  | V    |
| $I_D$     | drain current        | $T_{mb} = 25\text{ °C}$ ; $V_{GS} = 10\text{ V}$ ; Fig. 1                   | [1] | -   | 75  | A    |
|           |                      | $T_{mb} = 100\text{ °C}$ ; $V_{GS} = 10\text{ V}$ ; Fig. 1                  | [1] | -   | 59  | A    |
| $I_{DM}$  | peak drain current   | $T_{mb} = 25\text{ °C}$ ; pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; Fig. 4 |     | -   | 331 | A    |

| Symbol                      | Parameter                                    | Conditions   |                        | Min | Max | Unit |
|-----------------------------|--|--|------------------------|-----|-----|------|
| $P_{tot}$                   | total power dissipation                      | $T_{mb} = 25\text{ °C}$ ; <a href="#">Fig. 2</a>   |                        | -   | 96  | W    |
| $T_{stg}$                   | storage temperature                          |  |                        | -55 | 175 | °C   |
| $T_j$                       | junction temperature                         |  |                        | -55 | 175 | °C   |
| <b>Source-drain diode</b>   |  |  |                        |     |     |      |
| $I_S$                       | source current                               | $T_{mb} = 25\text{ °C}$  | <a href="#">[1]</a>    | -   | 75  | A    |
| $I_{SM}$                    | peak source current                          | pulsed; $t_p \leq 10\text{ }\mu\text{s}$ ; $T_{mb} = 25\text{ °C}$   |                        | -   | 331 | A    |
| <b>Avalanche ruggedness</b> |  |  |                        |     |     |      |
| $E_{DS(AL)S}$               | non-repetitive drain-source avalanche energy | $I_D = 75\text{ A}$ ; $V_{sup} \leq 40\text{ V}$ ; $R_{GS} = 50\text{ }\Omega$ ;<br>$V_{GS} = 10\text{ V}$ ; $T_{j(init)} = 25\text{ °C}$ ; unclamped;<br><a href="#">Fig. 3</a> | <a href="#">[2][3]</a> | -   | 44  | mJ   |

- [1] Continuous current is limited by package.
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [3] Refer to application note AN10273 for further information.



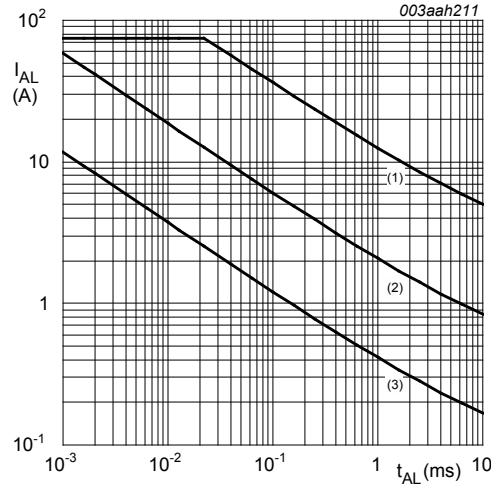


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)  $T_{j (init)} = 25^{\circ}C$ ; (2)  $T_{j (init)} = 150^{\circ}C$ ; (3) Repetitive Avalanche

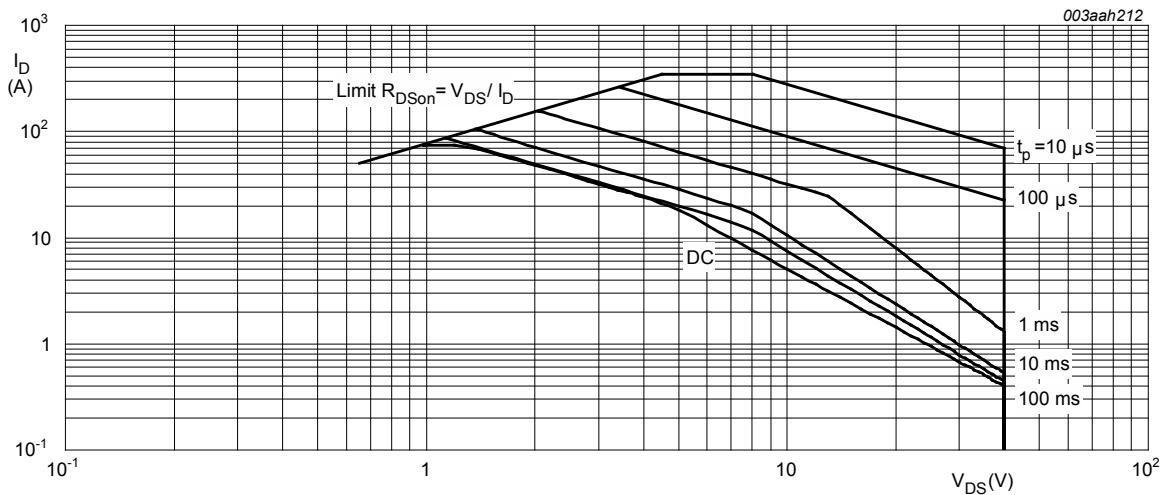


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^{\circ}C$ ;  $I_{DM}$  is a single pulse

## 6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol         | Parameter   | Conditions            | Min | Typ | Max  | Unit |
|----------------|---|-----------------------|-----|-----|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5                | -   | -   | 1.56 | K/W  |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient       | vertical in still air | -   | 60  | -    | K/W  |

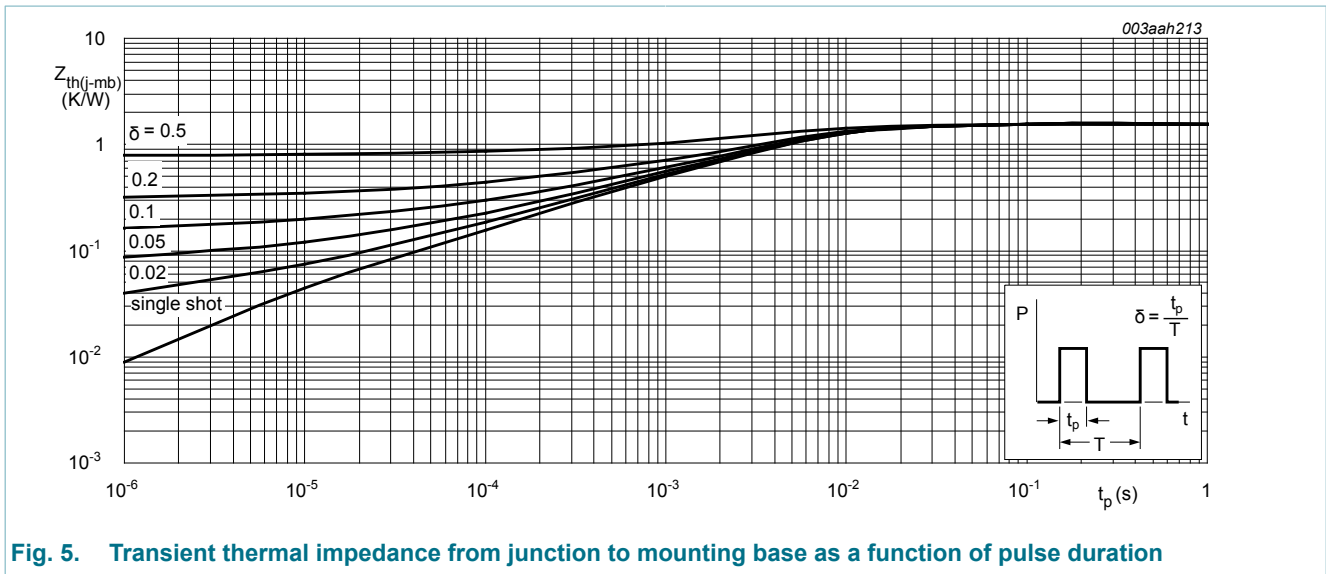


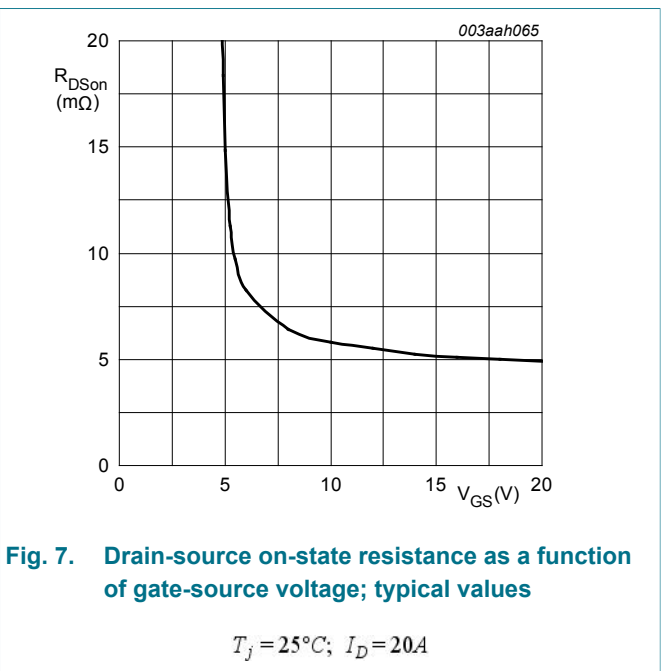
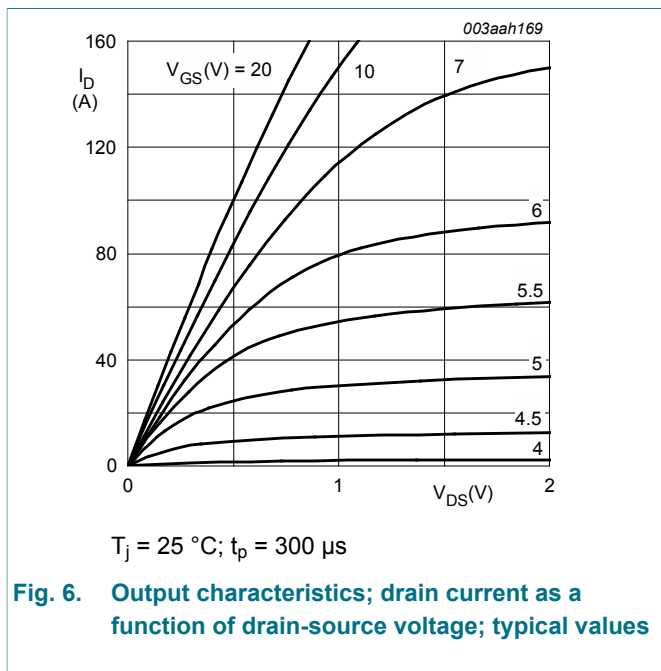
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 7. Characteristics

Table 7. Characteristics

| Symbol                         | Parameter                        | Conditions   | Min | Typ  | Max  | Unit       |
|--------------------------------|----------------------------------|--|-----|------|------|------------|
| <b>Static characteristics</b>  |                                  |  |     |      |      |            |
| $V_{(BR)DSS}$                  | drain-source breakdown voltage   | $I_D = 250 \mu A; V_{GS} = 0 V; T_J = 25 \text{ }^\circ C$   | 40  | -    | -    | V          |
|                                |                                  | $I_D = 250 \mu A; V_{GS} = 0 V; T_J = -55 \text{ }^\circ C$  | 36  | -    | -    | V          |
| $V_{GS(th)}$                   | gate-source threshold voltage    | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_J = 25 \text{ }^\circ C;$<br><a href="#">Fig. 9; Fig. 10</a>         | 2.4 | 3    | 4    | V          |
|                                |                                  | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_J = -55 \text{ }^\circ C;$<br><a href="#">Fig. 10</a>                | -   | -    | 4.5  | V          |
|                                |                                  | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_J = 175 \text{ }^\circ C;$<br><a href="#">Fig. 10</a>                | 1   | -    | -    | V          |
| $I_{DSS}$                      | drain leakage current            | $V_{DS} = 40 \text{ V}; V_{GS} = 0 \text{ V}; T_J = 25 \text{ }^\circ C$                                     | -   | 0.05 | 1    | $\mu A$    |
|                                |                                  | $V_{DS} = 40 \text{ V}; V_{GS} = 0 \text{ V}; T_J = 175 \text{ }^\circ C$                                    | -   | -    | 500  | $\mu A$    |
| $I_{GSS}$                      | gate leakage current             | $V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_J = 25 \text{ }^\circ C$                                     | -   | 2    | 100  | nA         |
|                                |                                  | $V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_J = 25 \text{ }^\circ C$                                    | -   | 2    | 100  | nA         |
| $R_{DSon}$                     | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 20 \text{ A}; T_J = 25 \text{ }^\circ C;$<br><a href="#">Fig. 11</a>           | -   | 5.8  | 7.4  | m $\Omega$ |
|                                |                                  | $V_{GS} = 10 \text{ V}; I_D = 20 \text{ A}; T_J = 175 \text{ }^\circ C;$<br><a href="#">Fig. 12; Fig. 11</a> | -   | -    | 14.1 | m $\Omega$ |
| <b>Dynamic characteristics</b> |                                  |  |     |      |      |            |
| $Q_{G(tot)}$                   | total gate charge                | $I_D = 20 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$<br><a href="#">Fig. 13; Fig. 14</a>      | -   | 24   | -    | nC         |
| $Q_{GS}$                       | gate-source charge               |  | -   | 5.6  | -    | nC         |
| $Q_{GD}$                       | gate-drain charge                |  | -   | 7.4  | -    | nC         |

| Symbol                    | Parameter                    | Conditions  | Min | Typ  | Max  | Unit |
|---------------------------|------------------------------|---|-----|------|------|------|
| $C_{iss}$                 | input capacitance            | $V_{GS} = 0\text{ V}; V_{DS} = 25\text{ V}; f = 1\text{ MHz};$                                    | -   | 1300 | 1730 | pF   |
| $C_{oss}$                 | output capacitance           | $T_j = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 15</a>   | -   | 260  | 312  | pF   |
| $C_{rss}$                 | reverse transfer capacitance |   | -   | 144  | 197  | pF   |
| $t_{d(on)}$               | turn-on delay time           | $V_{DS} = 30\text{ V}; R_L = 1.5\text{ }\Omega; V_{GS} = 10\text{ V};$                            | -   | 11   | -    | ns   |
| $t_r$                     | rise time                    | $R_{G(ext)} = 5\text{ }\Omega$  | -   | 9    | -    | ns   |
| $t_{d(off)}$              | turn-off delay time          |   | -   | 21   | -    | ns   |
| $t_f$                     | fall time                    |   | -   | 9    | -    | ns   |
| $L_D$                     | internal drain inductance    | from upper edge of drain mounting base to center of die   | -   | 2.5  | -    | nH   |
| $L_S$                     | internal source inductance   | from source lead to source bonding pad  | -   | 7.5  | -    | nH   |
| <b>Source-drain diode</b> |                              |   |     |      |      |      |
| $V_{SD}$                  | source-drain voltage         | $I_S = 20\text{ A}; V_{GS} = 0\text{ V}; T_j = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 16</a> | -   | 0.86 | 1.2  | V    |
| $t_{rr}$                  | reverse recovery time        | $I_S = 20\text{ A}; di_S/dt = -100\text{ A}/\mu\text{s}; V_{GS} = 0\text{ V};$                    | -   | 18.6 | -    | ns   |
| $Q_r$                     | recovered charge             | $V_{DS} = 25\text{ V}$  | -   | 10.7 | -    | nC   |



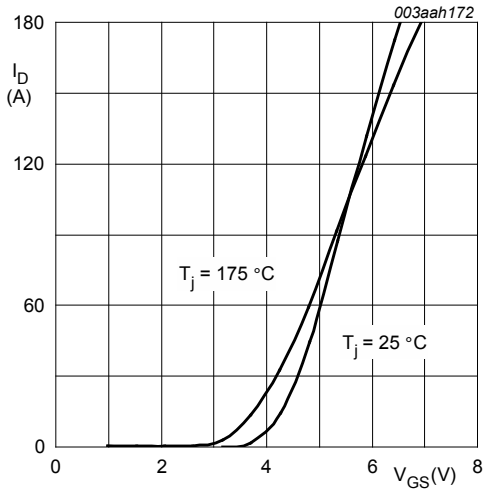


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

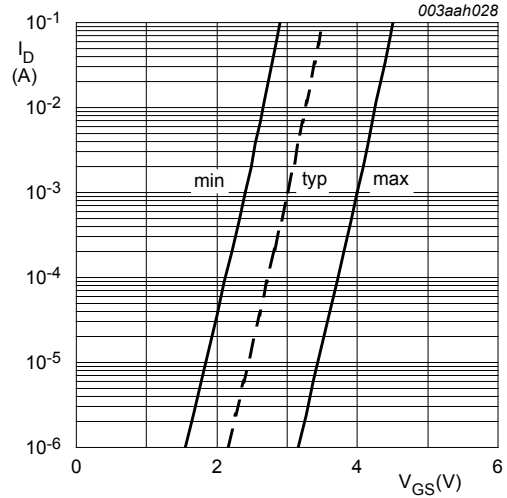


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25^\circ C; V_{DS} = 5V$$

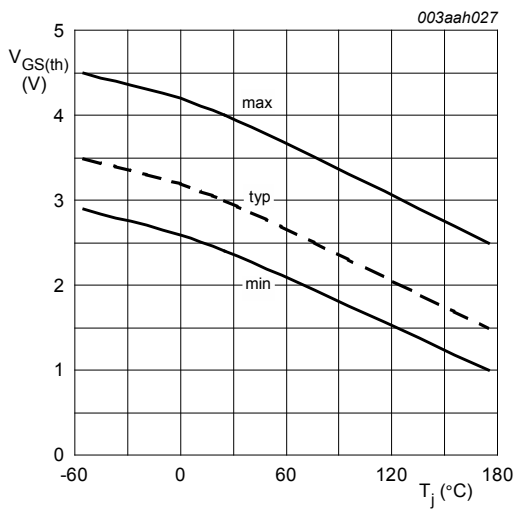


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$$

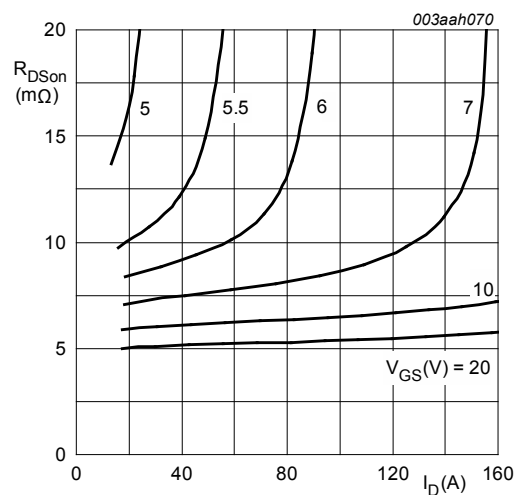


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^\circ C; t_p = 300 \mu s$$

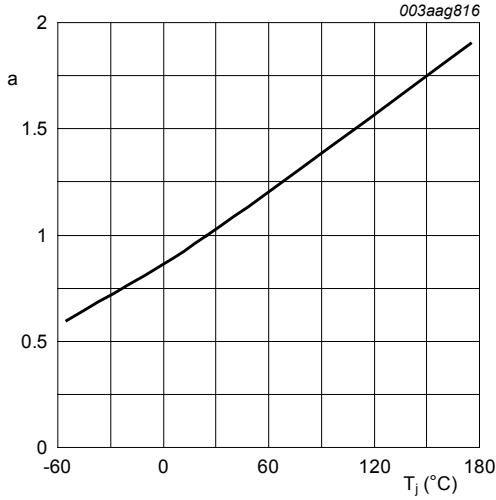


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon(25\text{ }^\circ\text{C})}}$$

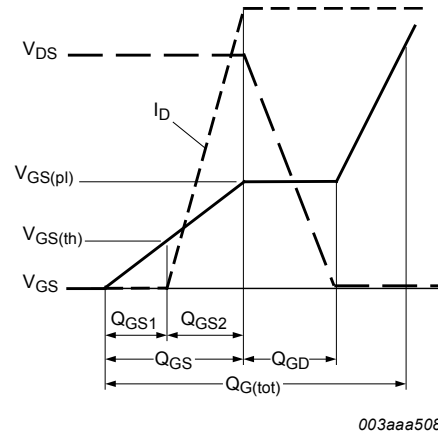


Fig. 13. Gate charge waveform definitions

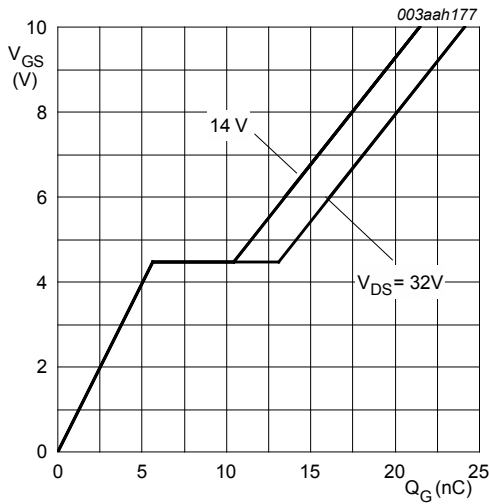


Fig. 14. Transient thermal impedance from junction to mounting base as a function of pulse duration

$$T_j = 25^\circ\text{C}; I_D = 15A$$

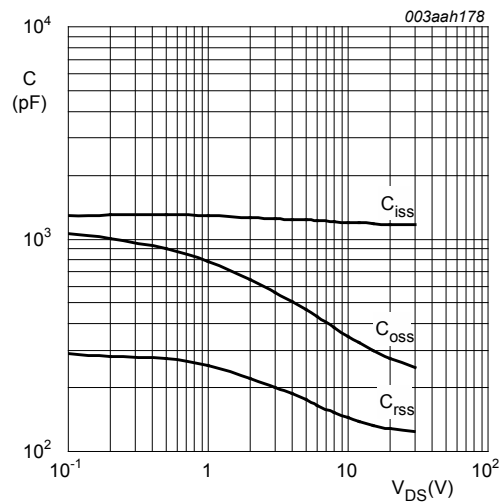


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0V; f = 1MHz$$

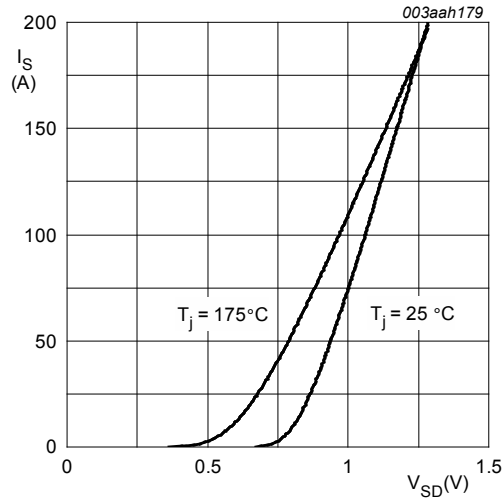


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$$V_{GS} = 0V$$

### 8. Package outline

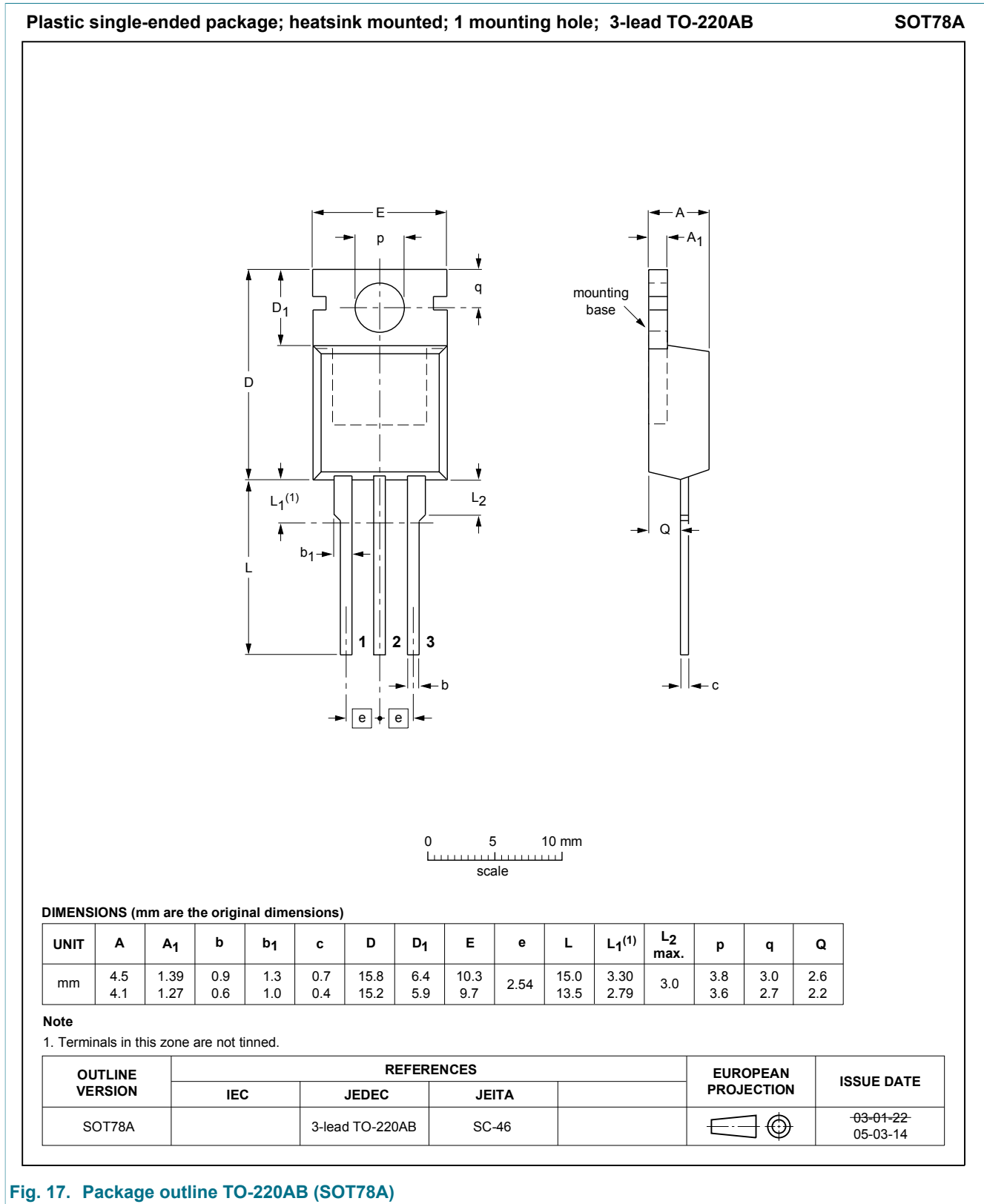


Fig. 17. Package outline TO-220AB (SOT78A)

## 9. Legal information

### 9.1 Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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